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(57) Abstract :

ABSTRACT GRADED COPPER INDIUM GALLIUM SELENIDE (CISG) SOLAR CELL The present disclosure discloses a graded copper indium gallium selenide (CISG) solar cell (102), comprising a CIGS layers (104) utilizing a linear grading, a parabolic grading, and a beta-grading to obtain an optimum composition for the CIGS layer in order to generate electricity. FIG. 1

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